

# iSpace+™ miniRAFS Spec

## High-Reliability Rubidium Atomic Frequency Source



### Applications

Deep space mission | Secure telecom payload | Earth observation satellites | Science missions

### Key Features

- Low temperature sensitivity
- Good short term stability
- Small volume
- Excellent long term stability
- Rb lamp extended life expectancy (>20 years)

### Key Applications

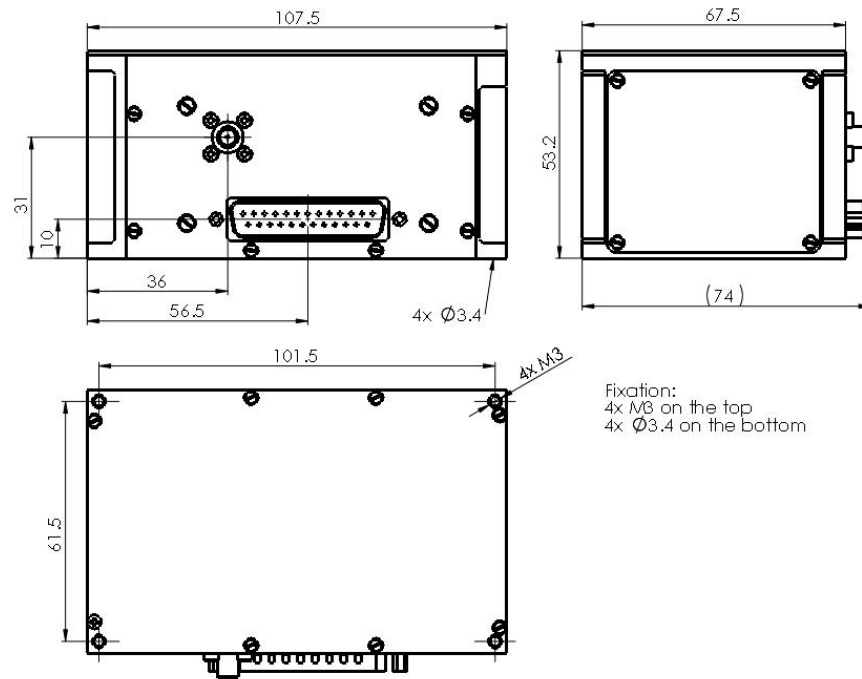
- Space scientific missions
- Secure satellite communications
- Tracking and guidance control
- Advanced low satellite orbit digital communications

### Key Product Spec

- |  |   |
|--|---|
| • Volume                                 | 0.39 liters   |
| • Thermal sensitivity over -20°C to 60°C | $< \pm 7 \times 10^{-13} / ^\circ\text{C}$                              |
| • Stability                              | $< 2 \times 10^{-13} / 1000\text{sec}$                                  |
| • Long term stability                    | $< 3 \times 10^{-11} / \text{month} / < 1 \times 10^{-9}$ over 10 years |
| • Power supply with DC-DC optional conv. | compatible with 28V or 50V power bus                                    |
| • Output frequency                       | 10MHz   |

## Package

(all dimensions in millimeters)



## Pin functions & layout (J2: 25 pins D\_SUB)

N°	I/O	Designation	Description
1	O	10MHz	10MHz sine output (OdBm / 50Ω)
2	I/O	GND	Power return
3	O	SYNCH+	150KHz (duty cycle of 50%) derived from 60MHz main output frequency (frequency divider of 480).(used with DC-DC stackable converter)
4	O	SYNCH-	Inverse of SYNCH+
5	I/O	GND	Power return
6	O	LOCK	Lock indicator
7	O	RB_SIGNAL	Atomic signal level monitoring (0 to 5V range)
8	I	T_LAMP_ADJ	This pin shall be Not Connected (NC) for operation under vacuum. Under air condition, this pin shall be connected to GND (pin 9).
9	I/O	GND	Power return
10	O	VREF	+5V reference (Imax=1mA, 4.95 to 5.05V range)
11	I/O	GND	Power return
12	I	VAD	+16V input voltage (15.5 to 16.5V range)
13	I	VDD	+3.5V input voltage (3.5 to 5V range)
14	I/O	GND	Power return
15	I/O	GND	Power return
16	I	GND	Power return
17	I	GND	Power return
18	O	HEAT_CELL	Level of the heater control for the cell (0 to 5V range)
19	O	HEAT_LAMP	Level of the heater control for the lamp (0 to 5V range)
20	O	RB_LIGHT	Light level intensity monitoring (0 to 5V range)
21	O	VC_MON	Voltage control of VCXO (0 to 5V range)
22	I	FREQ_ADJ	Analogue frequency adjustment (0 to 5V range)
23	I/O	GND	Power return
24	I	VAD	+16V input voltage (15.5 to 16.5V range)
25	I/O	GND	Power return

## SPECIFICATIONS

Parameter	value	Unit
<b>PERFORMANCE METRICS</b>		
Frequency	Main (Sinus on SMA connector) Auxiliary (sinus wave )	60.00 10.00 MHz MHz
Frequency accuracy after launch & commissioning phase : Under vacuum conditions at delivery	$\leq 2 \times 10^{-10}$ $\leq 1 \times 10^{-10}$	
Freq. Stab Short Term (max )	1 sec 10 sec 100 sec 1000 sec 10000 sec (drift removed) flicker floor (drift removed)	$1 \times 10^{-11}$ $3 \times 10^{-12}$ $1 \times 10^{-12}$ $3 \times 10^{-13}$ $1 \times 10^{-13}$ $2 \times 10^{-13}$
Freq. Stab Long Term (typical)	$< 1 \times 10^{-10}$	Per year
Outputs 60MHz Signal Level	7 ±1 Auxiliary 10MHz 0 ±1	dBm dBm
Return loss power ON conditions (nominal output impedance 50 Ω )/60MHz	>20	dB
Spurious Signals (60MHz) (band +/- 2MHz) Outside	< -80 < -60	dB dB
Harmonics	< -30	dBc
Phase Noise (60 MHz)	1Hz 10 Hz 100 Hz 1000 Hz 10000 Hz 100000 Hz	-64 -84 -129 -134 -135 -135 dBc dBc dBc dBc dBc dBc
<b>PHYSICAL</b>		
Envelope and dimensions	L=107.5 W=67.5 H=53.5	mm mm mm
Mass	0.45	Kg
Stiffness	> 100	Hz
Design Lifetime	> 20	Years
<b>ELECTRICAL INTERFACES</b>		
<b>ELECTRICAL POWER</b>		
Digital power voltage range	3.5 to 5	V
Current	< 0,2	A
Analog power voltage range	15.5 to 16.5	V
Current	< 0,6	A
<b>TM</b>		
TM List	Lock Indication Rb Light Rb Signal VCXO control Rb Cell heater control Rb Lamp Heater control	Open collector 0-5 5-0 0-5 0-5 0-5 0-5 V V V V V V

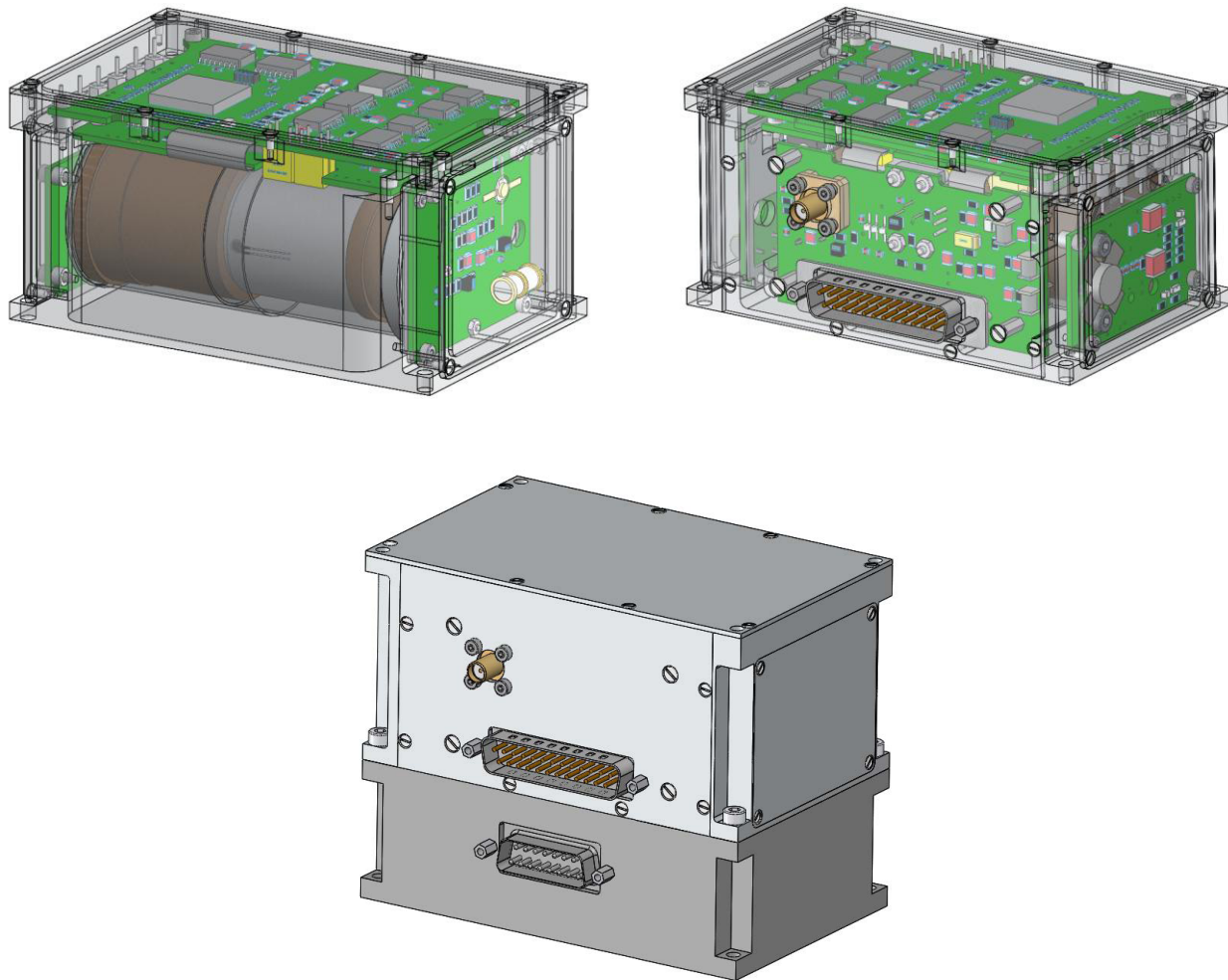
<b>STRUCTURAL &amp; MECHANICAL INTERFACES</b>			
Surface Finish-Flatness	Overall contact area Local flatness Roughness	< 0.2 < 0.1/100 < 3.2	mm mm/mm µm
Interconnections	RF outputs TM & Power	SMA (J01) SUB-D 25 (J02)	
<b>ENVIRONMENTAL &amp; THERMAL INTERFACES</b>			
Interface Heat Flux		<0.3	W/cm <sup>2</sup>
Power dissipation	During warm-up During nominal operation	< 15 < 10	W W
Temperature limits (under vac conditions)	Operating Short-term variation Acceptance Qualification Cold start Non-operating	-15 to +55 ≤ ±/ - 1 -20 to +60 -25 to + 65 -25 -55 to + 85	°C °C °C °C °C °C
Vacuum level		10 <sup>-5</sup>	mbar
Magnetic field		< +/- 1	Gauss
Radiation Environment.		LEO/MEO/GEO orbits	
<b>ORBITAL LIFETIME &amp; MTBF</b>			
Reliability figure (LEO,MEO)		<1000	FIT
Design Lifetime		> 20	Years

## miniRAFS Description

The miniature Rubidium Atomic Frequency Standard (miniRAFS) is a state-of-the-art ultra-stable atomic clock able to deliver a frequency accuracy better than  $1E-9$  over 10 years operations in orbit along with very good short and mid-term frequency stability.

The miniRAFS unit is a complete atomic clock within very small volume. It can be complemented on request with an Electronic Power Conditioning name "EPC" which includes the DC/DC converter and the electrical interface to the satellite.

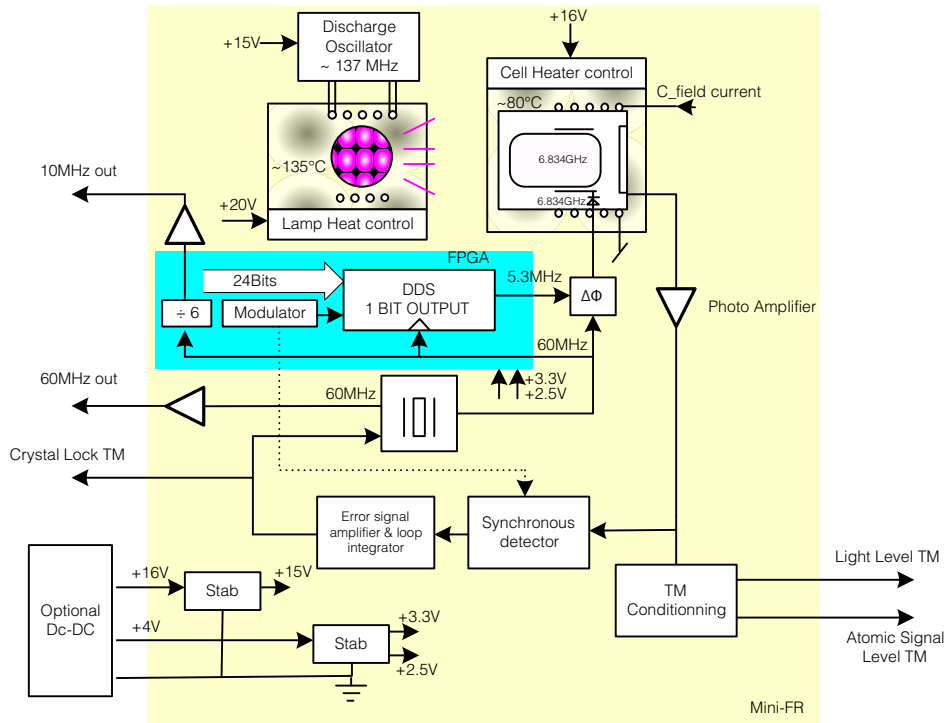
The EPC design could be adapted for specific satellite requirements.



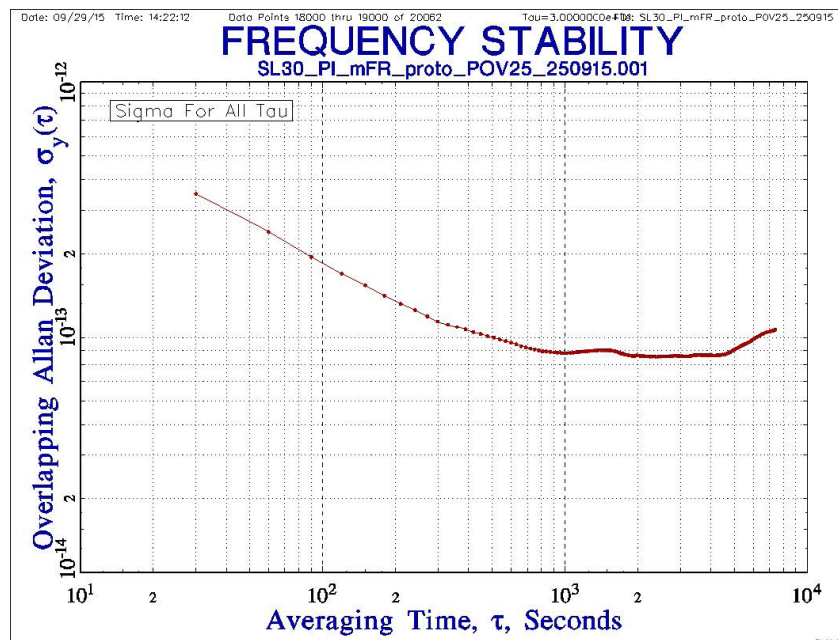
miniRAFS with OPTIONAL EPC module

## miniRAFS General Function & Block Diagram

The miniRAFS is a complete Rb clock module. The Rb clock essentially consists of a voltage-controlled crystal oscillator (VCXO) which is locked to a highly stable atomic transition in the ground state of the Rb87 isotope. While the frequency of the VCXO is at the convenient standard frequency of 10 MHz, the Rb clock frequency is at 6.834 GHz in the microwave range. The link between the two frequencies is done through a phase-stabilized frequency multiplication scheme whereby a synthesized frequency is admixed to enable exact matching.



miniRAFS Functional Block Diagram



miniRAFS Typical Short Term Stability Performance